



RB751W T-40 SCHOTTKY BARRIER DIODE

for high speed switching and detection applications

Features

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

Marking Code: " D "



Cathode

Anode



SOD-523

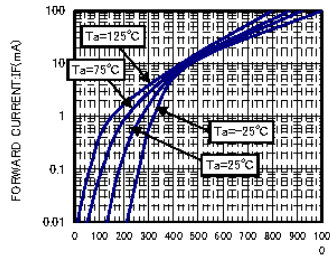
Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	40	V
Reverse Voltage	V_R	30	V
Mean Rectifying Current	I_O	30	mA
Peak Forward Surge Current (60 Hz, 1 Cycle)	I_{FSM}	200	mA
Junction Temperature	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 40 to + 125	$^\circ\text{C}$

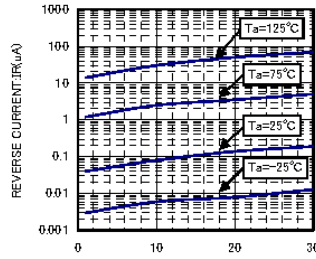
Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Typ.	Max.	Unit
Forward Voltage at $I_F = 1\text{ mA}$	V_F	-	0.37	V
Reverse Current at $V_R = 30\text{ V}$	I_R	-	0.5	μA
Capacitance Between Terminals at $V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_T	2	-	pF

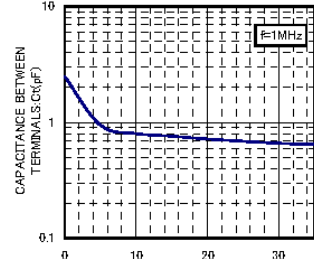
Note: ESD sensitive product handling required.



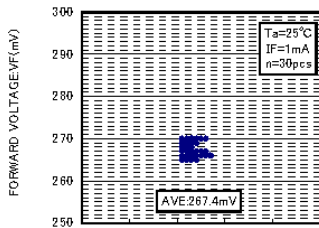
VF-IF CHARACTERISTICS
VF 分布



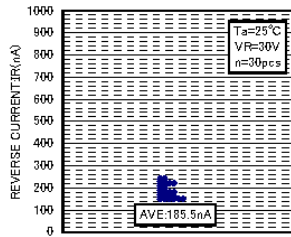
VR-IR CHARACTERISTICS



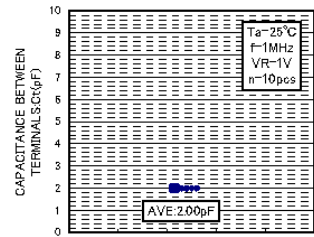
VR-Ct CHARACTERISTICS



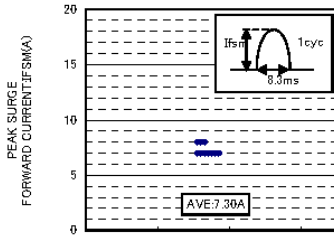
VF DISPERSION MAP



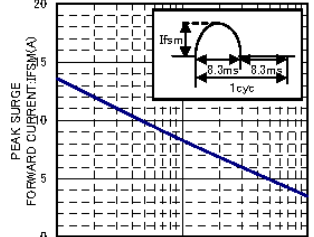
IR DISPERSION MAP



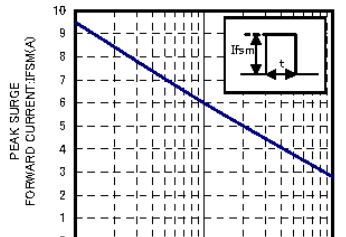
Ct DISPERSION MAP



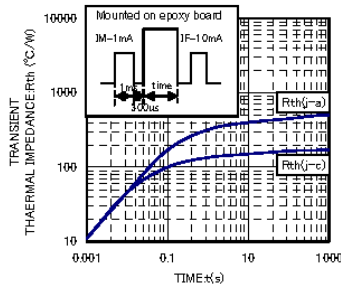
IFSM DISPERSION MAP



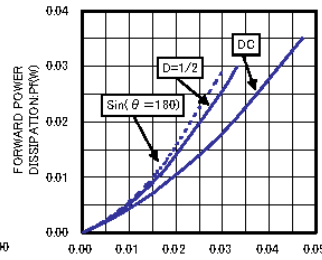
IFSM-CYCLE CHARACTERISTICS



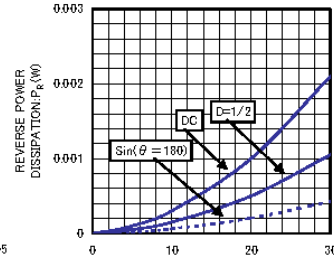
IFSM-t CHARACTERISTICS



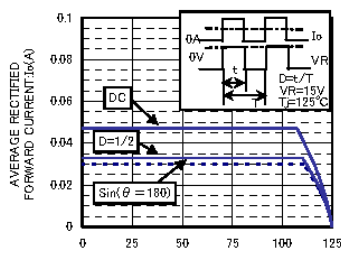
Rth-t CHARACTERISTICS



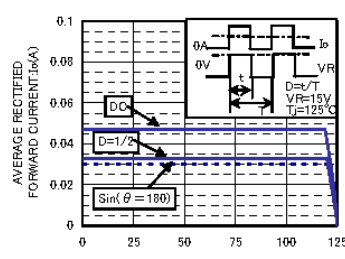
AVERAGE RECTIFIED FORWARD CURRENT I_o -PF CHARACTERISTICS



REVERSE VOLTAGE V_R - P_k CHARACTERISTICS



AMBIENT TEMPERATURE: T_a (°C)
Derating Curve (I_o - T_a)



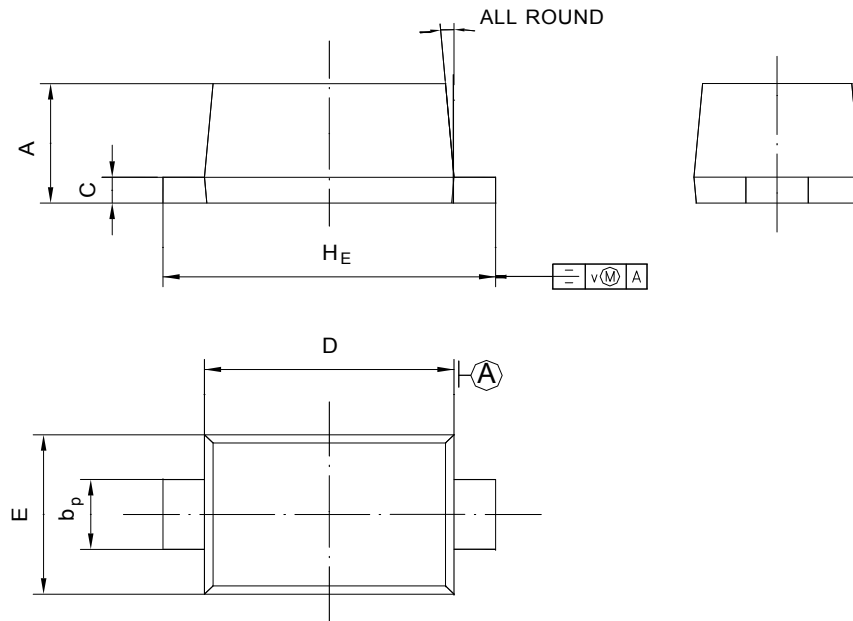
CASE TEMPERATURE: T_c (°C)
Derating Curve (I_o - T_c)



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.68	0.4	0.135	1.25	0.85	1.7	0.1	5°
	0.58	0.3	0.100	1.15	0.75	1.5		